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Schematic diagram

NCE)

NCE15H10 XXXXX

Marking and pin assignment

GDS TO-220-3L top view

(1) GO

# NCE N-Channel Enhancement Mode Power MOSFET

#### Description

The NCE15H10 uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. This device is suitable for use in PWM, load switching and general purpose applications.

#### **General Features**

- V<sub>DS</sub> =150V,I<sub>D</sub> =100A
  - $R_{DS(ON)} < 12m\Omega @ V_{GS} = 10V$  (Typ:9.8m $\Omega$ )
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Special designed for convertors and power controls
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

#### Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

## 100% UIS TESTED!

100% ΔVds TESTED!

#### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE15H10	NCE15H10	TO-220-3L	-	-	-

#### Absolute Maximum Ratings (Tc =25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	VDS	150	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	Ι <sub>D</sub>	100	А	
Drain Current-Continuous(Tc=100 ℃)	l₀ (100°C)	70	А	
Pulsed Drain Current	I <sub>DM</sub>	400	A	
Maximum Power Dissipation	PD	370	W	
Derating factor		2.47	W/℃	
Single pulse avalanche energy <sup>(Note 5)</sup>	Eas	1100	mJ	
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 175	°C	



#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case(Note 2)	R <sub>θJC</sub>	0.41	°C/W
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#### Electrical Characteristics (Tc=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	150	170	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =150V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	2	3.2	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =40A	-	9.8	12	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =25V,I <sub>D</sub> =40A	150	-	-	S
Dynamic Characteristics (Note4)			1			
Input Capacitance	Clss			11800	-	PF
Output Capacitance	Coss		-	365	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHZ	-	294	-	PF
Switching Characteristics (Note 4)		-				
Turn-on Delay Time	t <sub>d(on)</sub>		-	32.5	-	nS
Turn-on Rise Time	tr	VDD=75V, RL=1.5Ω	-	30	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	V <sub>DS</sub> =75V,V <sub>GS</sub> =0V, F=1.0MHz VDD=75V, RL=1.5Ω ,RG=2.5Ω,VGS=10V V <sub>DS</sub> =75V,I <sub>D</sub> =20A, V <sub>GS</sub> =10V		113	-	nS
Turn-Off Fall Time	tf		-	48	-	nS
Total Gate Charge	Qg	)/ <u>75</u> )// 00A	-	280	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	50	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	93	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =100A	-	-	1.2	V
Diode Forward Current (Note 2)	ls		-	-	100	A
Reverse Recovery Time	t <sub>rr</sub>	Tj=25℃,I <sub>F</sub> =100A,di/dt=100A/µs	-	55	-	nS
Reverse Recovery Charge	Qrr	(Note3)	-	182	-	nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligib	le (turn	on is dom	ninated by	LS+LD)

#### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

**2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.

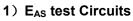
**3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

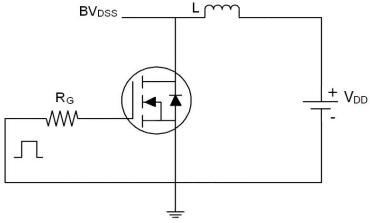
4. Guaranteed by design, not subject to production

5. EAS condition: Tj=25 $^\circ C$  ,V\_DD=50V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$ 

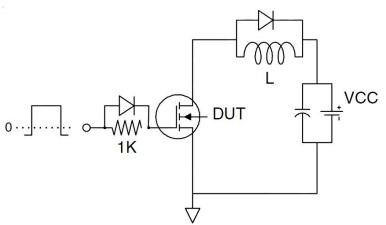


# Test circuit

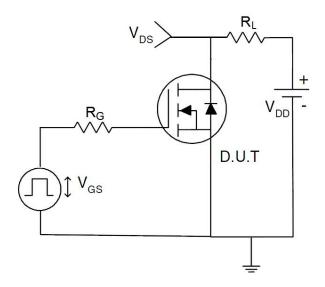




### 2) Gate charge test Circuit:

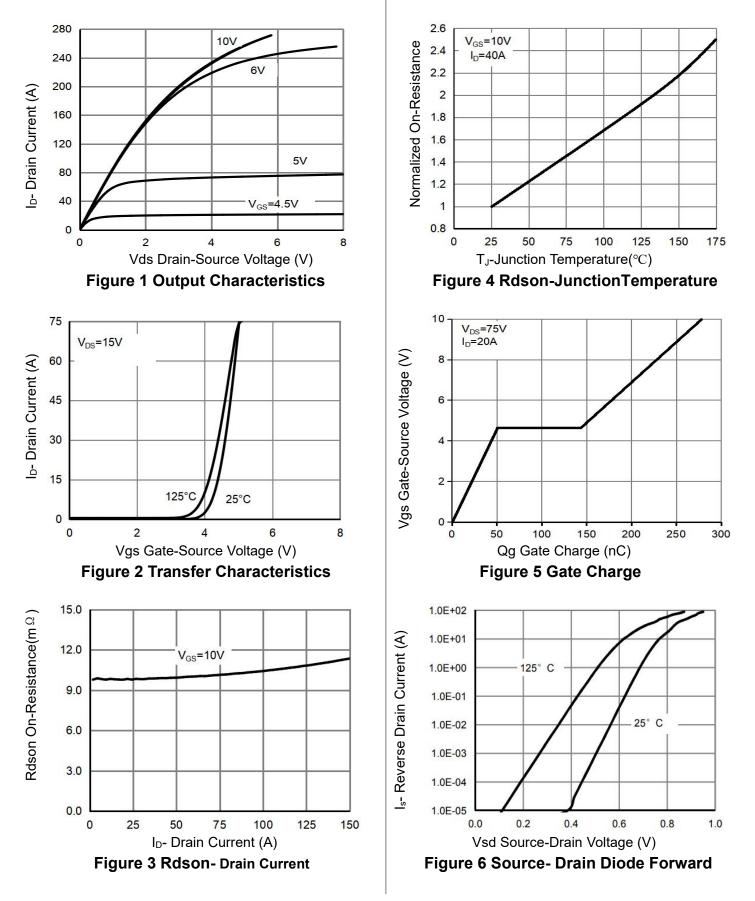


3) Switch Time Test Circuit:



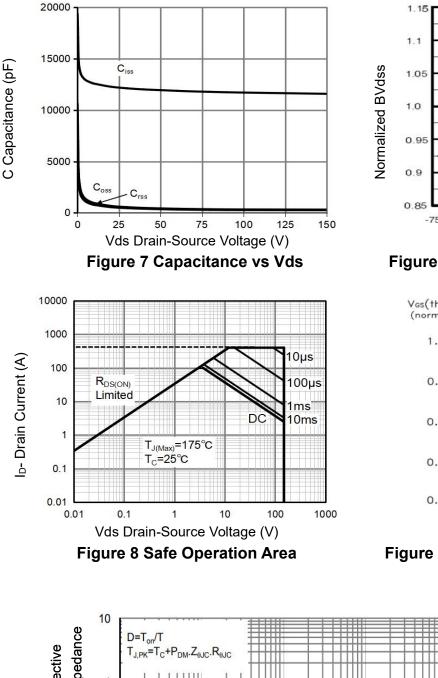


### **Typical Electrical and Thermal Characteristics (Curves)**





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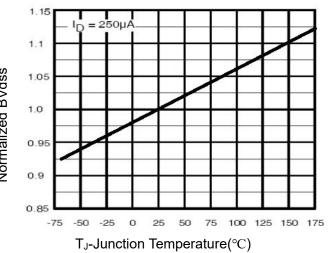


Figure 9 BV<sub>DSS</sub> vs Junction Temperature

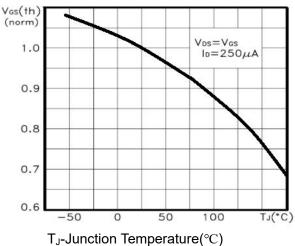
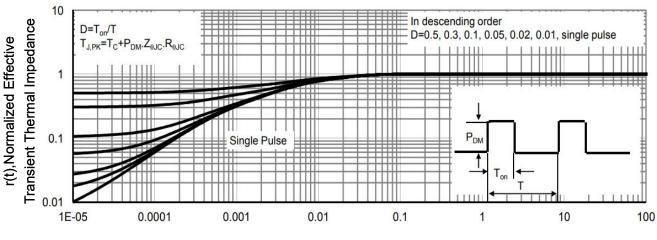
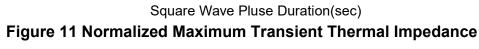


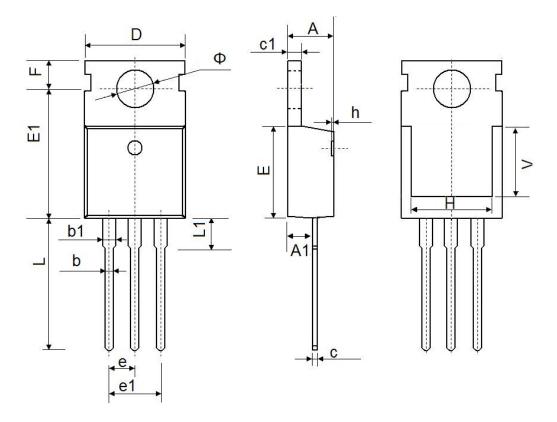
Figure 10 V<sub>GS(th)</sub> vs Junction Temperature







## TO-220-3L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500 REF.		0.295 REF.		
Ф	3.400	3.800	0.134	0.150	



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